

## AD8691/AD8692/AD8694

### FEATURES

- Offset voltage: 400  $\mu\text{V}$  typ
- Low offset voltage drift: 6  $\mu\text{V}/^\circ\text{C}$  max (AD8692/AD8694)
- Very low input bias currents: 1 pA max
- Low noise: 8 nV/ $\sqrt{\text{Hz}}$
- Low distortion: 0.0006%
- Wide bandwidth: 10 MHz
- Unity-gain stable
- Single-supply operation: 2.7 V to 6 V

### APPLICATIONS

- Photodiode amplification
- Battery-powered instrumentation
- Medical instruments
- Multipole filters
- Sensors
- Portable audio devices

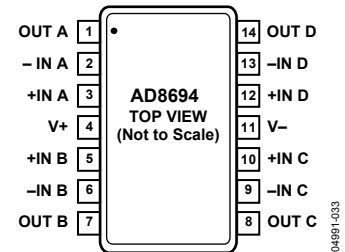
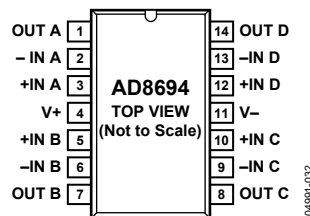
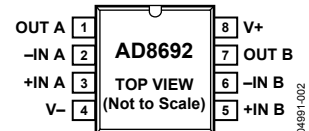
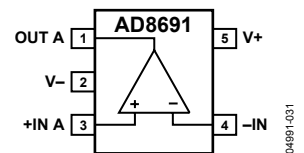
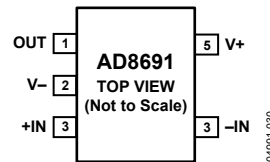
### GENERAL DESCRIPTION

The AD8691, AD8692, and AD8694 are low cost, single, dual, and quad rail-to-rail output, single-supply amplifiers featuring low offset and input voltages, low current noise, and wide signal bandwidth. The combination of low offset, low noise, very low input bias currents, and high speed make these amplifiers useful in a wide variety of applications. Filters, integrators, photodiode amplifiers, and high impedance sensors all benefit from this combination of performance features. Audio and other ac applications benefit from the wide bandwidth and low distortion of these devices.

#### Rev. B

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

### PIN CONFIGURATIONS



Applications for these amplifiers include PA controls, laser diode control loops, portable and loop-powered instrumentation, audio amplification for portable devices, and ASIC input and output amplifiers.

The small SC70 and TSOT package options for the AD8691 allow it to be placed next to sensors, thereby reducing external noise pickup.

The AD8691, AD8692, and AD8694 are specified over the extended industrial temperature range of  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . The AD8691 single is available in 5-lead SC70 and TSOT packages. The AD8692 dual is available in 8-lead MSOP and narrow SOIC surface-mount packages. The AD8694 quad is available in 14-lead TSSOP and narrow 14-lead SOIC packages.

**TABLE OF CONTENTS**

Electrical Characteristics .....	3	Typical Performance Characteristics .....	6
Absolute Maximum Ratings.....	5	Outline Dimensions .....	11
Thermal Characteristics .....	5	Ordering Guide .....	12
ESD Caution.....	5		

**REVISION HISTORY**

**3/05—Rev. A to Rev. B**

Added AD8694 ..... Universal

**1/05—Rev. 0 to Rev. A**

Added AD8691 ..... Universal  
Changes to Features..... 1  
Added Figure 1 and Figure 2..... 1  
Changes to Electrical Characteristics ..... 3  
Changes to Figure 6 caption..... 6  
Changes to Figure 9..... 6  
Updated Outline Dimensions ..... 11  
Changes to Ordering Guide ..... 11

**10/04—Revision 0: Initial Version**

## ELECTRICAL CHARACTERISTICS

$V_S = 2.7\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = -0.3\text{ V to } +1.6\text{ V}$ $V_{CM} = -0.1\text{ V to } +1.6\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.4	2.0	mV
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range			-0.3		+1.6	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.3\text{ V to } +1.6\text{ V}$ $V_{CM} = -0.1\text{ V to } +1.6\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$	68	90		dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to } 2.2\text{ V}$ $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to } 2.2\text{ V}$	90	250		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			2	12	$\mu\text{V}/^\circ\text{C}$
				1.3	6	$\mu\text{V}/^\circ\text{C}$
<b>INPUT CAPACITANCE</b>						
Common-Mode Input Capacitance	$C_{CM}$			5		pF
Differential Input Capacitance	$C_{DM}$			2.5		pF
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	2.64	2.66		V
Output Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	2.6	25	40	V
Short-Circuit Current	$I_{SC}$			$\pm 20$	60	mV
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}$ , $A_V = 1$		12		mA
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 2.7\text{ V to } 5.5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	80	95		dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	75	95	0.85	dB
					1.2	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		5		V/ $\mu\text{s}$
Settling Time	$t_S$	To 0.01%		1		$\mu\text{s}$
Gain Bandwidth Product	GBP			10		MHz
Phase Margin	$\phi_O$			60		Degrees
Total Harmonic Distortion + Noise	THD + N	$G = 1$ , $R_L = 600\ \Omega$ , $f = 1\text{ kHz}$ , $V_O = 250\text{ mV p-p}$		0.003		%
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	$f = 0.1\text{ Hz to } 10\text{ Hz}$		1.6	3.0	$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		8	12	nV/ $\sqrt{\text{Hz}}$
	$e_n$	$f = 10\text{ kHz}$		6.5		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.05		pA/ $\sqrt{\text{Hz}}$

# AD8691/AD8692/AD8694

$V_S = 5.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 5^\circ\text{C}$ , unless otherwise noted.

**Table 2.**

Parameter	Symbol	Conditions	A Grade			Unit
			Min	Typ	Max	
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = -0.3\text{ V to }+3.9\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.9\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.4	2.0	mV
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range			-0.3		+3.9	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.3\text{ V to }+3.9\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.9\text{ V}; -40^\circ\text{C} < T_A < +125^\circ\text{C}$	70	95		dB
Large Signal Voltage Gain	$A_{VO}$	$V_O = 0.5\text{ V to }4.5\text{ V}, R_L = 2\text{ k}\Omega, V_{CM} = 0\text{ V}$ $V_O = 0.5\text{ V to }4.5\text{ V}, R_L = 2\text{ k}\Omega, V_{CM} = 0\text{ V}$	250	2000		V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$					$\mu\text{V}/^\circ\text{C}$
AD8691			2		12	$\mu\text{V}/^\circ\text{C}$
AD8692/AD8694			1.3		6	$\mu\text{V}/^\circ\text{C}$
<b>INPUT CAPACITANCE</b>						
Common-Mode Input Capacitance	$C_{CM}$			5		pF
Differential Input Capacitance	$C_{DM}$			2.5		pF
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C to }+125^\circ\text{C}$	4.96	4.98		V
			4.7	4.78		V
			4.6			V
Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C to }+125^\circ\text{C}$ $-40^\circ\text{C to }+125^\circ\text{C}$		20	40	mV
AD8691/AD8692				165	210	mV
AD8694				185	240	mV
AD8691/AD8692					290	mV
AD8694					370	mV
Short-Circuit Current	$I_{SC}$			$\pm 80$		mA
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}, A_V = 1$		10		$\Omega$
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 2.7\text{ V to }5.5\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	80	95		dB
			75	95		dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.95	1.05	mA
					1.3	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		5		V/ $\mu\text{s}$
Settling Time	$t_s$	To 0.01%		1		$\mu\text{s}$
Full Power Bandwidth	$BW_P$	<1% distortion		360		kHz
Gain Bandwidth Product	GBP			10		MHz
Phase Margin	$\phi_O$			65		Degrees
Total Harmonic Distortion + Noise	THD + N	$G = 1, R_L = 600\ \Omega, f = 1\text{ kHz}, V_O = 1\text{ V p-p}$		0.0006		%
<b>NOISE PERFORMANCE</b>						
Voltage Noise	$e_{n\text{ p-p}}$	$f = 0.1\text{ Hz to }10\text{ Hz}$		1.6	3.0	$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		8	12	nV/ $\sqrt{\text{Hz}}$
	$e_n$	$f = 10\text{ kHz}$		6.5		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.05		pA/ $\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 3.**

Parameters	Ratings
Supply Voltage	6 V
Input Voltage	$V_{SS} - 0.3 \text{ V to } V_{DD} + 0.3 \text{ V}$
Differential Input Voltage	$\pm 6 \text{ V}$
Output Short-Circuit Duration to GND	Observe derating curves
Storage Temperature Range	$-65^\circ\text{C to } +150^\circ\text{C}$
Operating Temperature Range	$-40^\circ\text{C to } +125^\circ\text{C}$
Junction Temperature Range	$-65^\circ\text{C to } +150^\circ\text{C}$
Lead Temperature Range (Soldering, 60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL CHARACTERISTICS

**Table 4.**

Package Type	$\theta_{JA}^1$	$\theta_{JC}$	Unit
8-Lead MSOP (RM)	210	45	$^\circ\text{C/W}$
8-Lead SOIC (R)	158	43	$^\circ\text{C/W}$
5-Lead TSOT (UJ-5)	207	61	$^\circ\text{C/W}$
5-Lead SC70 (KS)	376	126	$^\circ\text{C/W}$
14-Lead TSSOP (RU)	180	35	$^\circ\text{C/W}$
14-Lead SOIC (R)	120	36	$^\circ\text{C/W}$

<sup>1</sup>  $\theta_{JA}$  is specified for the worst-case conditions, that is, the device soldered in the circuit board for surface-mount packages.

## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



TYPICAL PERFORMANCE CHARACTERISTICS

$V_S = +5\text{ V}$  or  $\pm 2.5\text{ V}$ , unless otherwise noted.

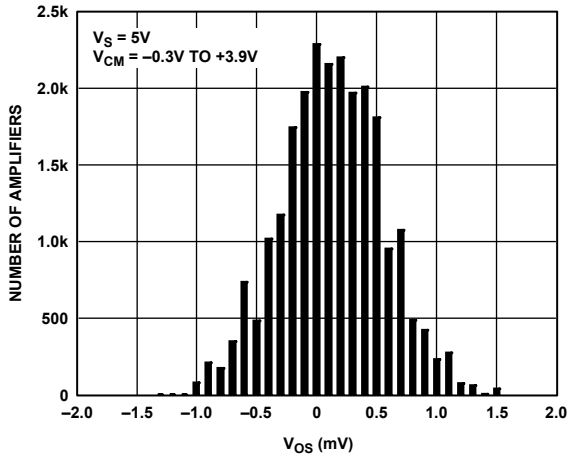


Figure 7. Input Offset Voltage Distribution

04991-003

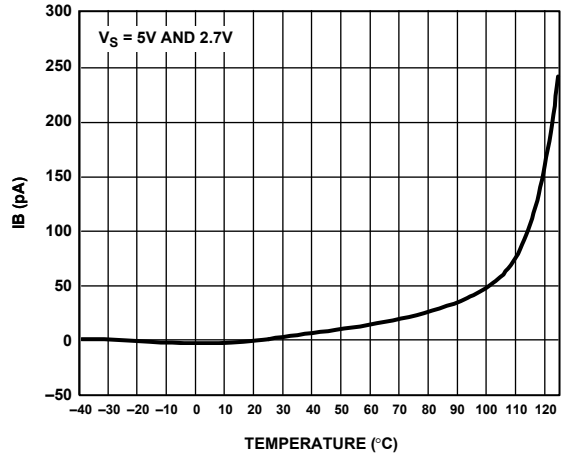


Figure 10. Input Bias Current vs. Temperature

04991-006

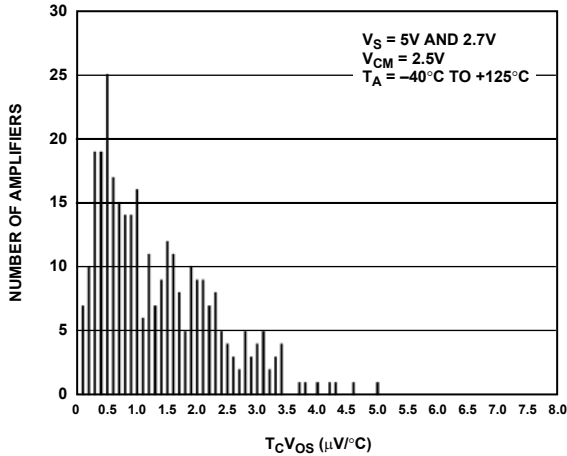


Figure 8. AD8692/AD8694 Input Offset Voltage Drift Distribution

04991-004

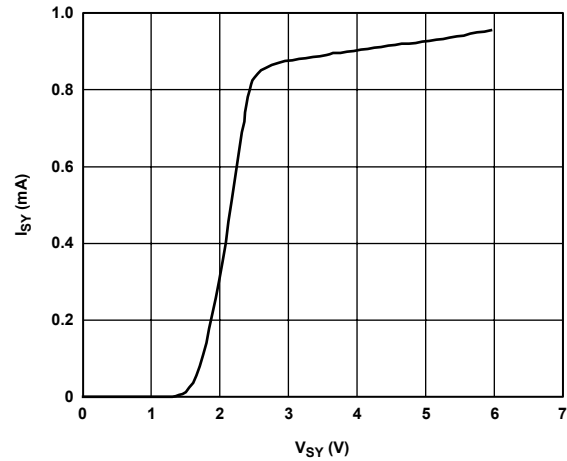


Figure 11. Supply Current vs. Supply Voltage

04991-007

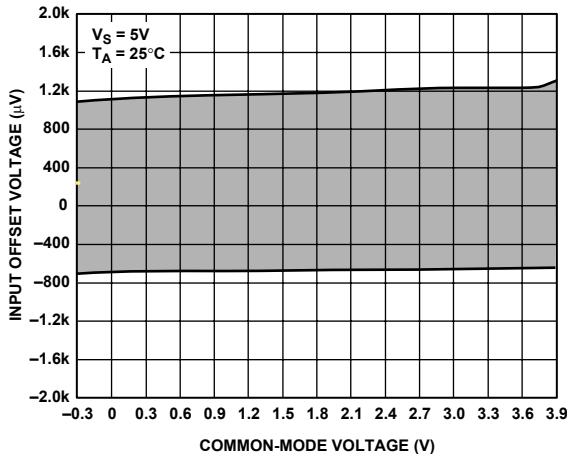


Figure 9. Input Offset Voltage vs. Common-Mode Voltage

04991-005

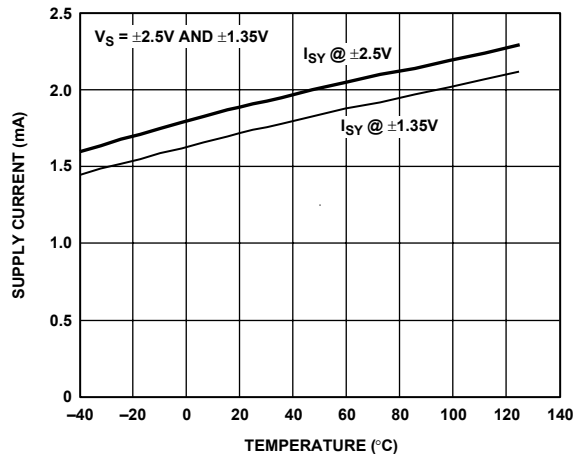


Figure 12. Supply Current vs. Temperature

04991-008

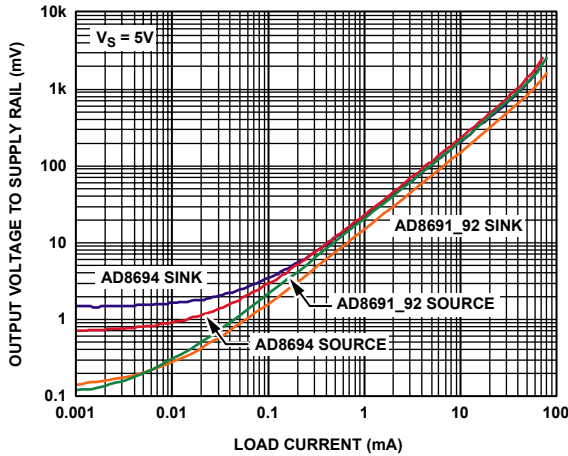


Figure 13. Output Voltage to Supply Rail vs. Load Current

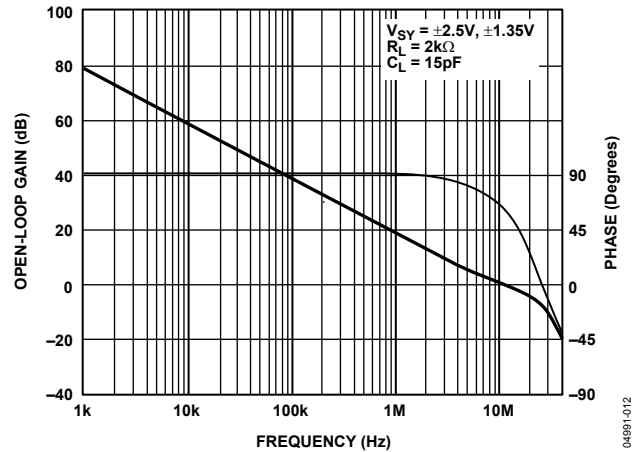


Figure 16. Open-Loop Gain and Phase vs. Frequency

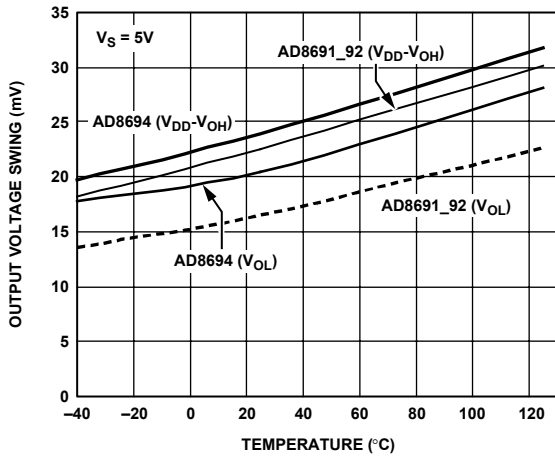


Figure 14. Output Voltage Swing vs. Temperature ( $I_L = 1 \text{ mA}$ )

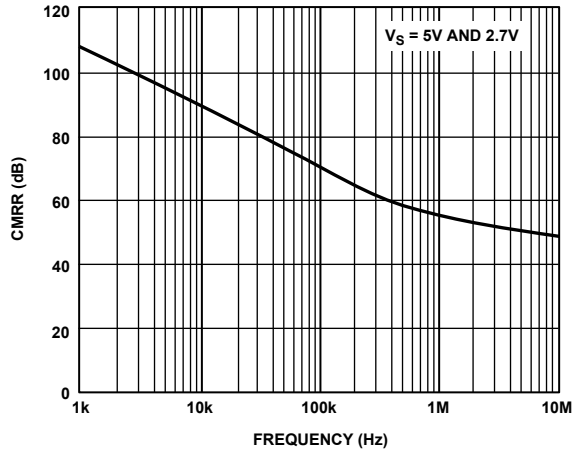


Figure 17. CMRR vs. Frequency

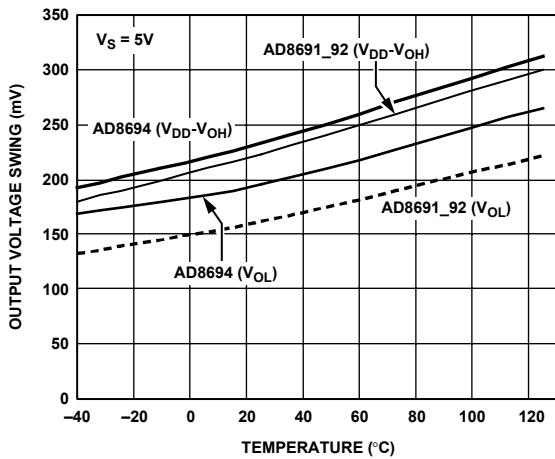


Figure 15. Output Voltage Swing vs. Temperature ( $I_L = 10 \text{ mA}$ )

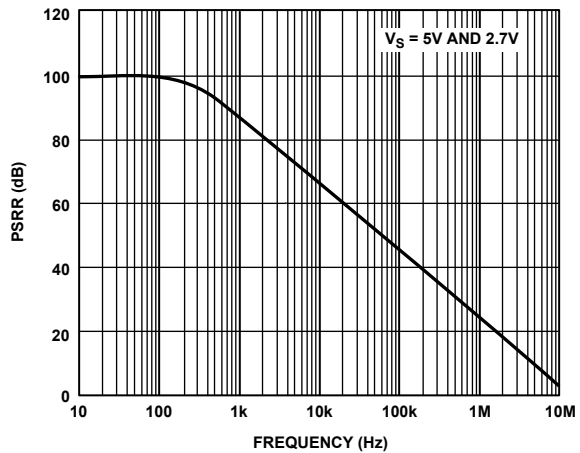


Figure 18. PSRR vs. Frequency

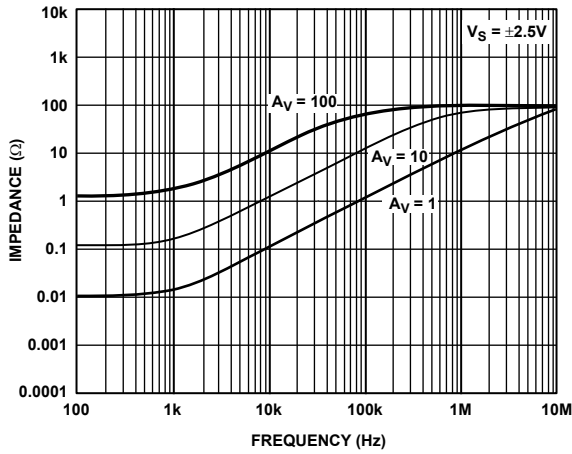


Figure 19. Closed-Loop Output Impedance vs. Frequency

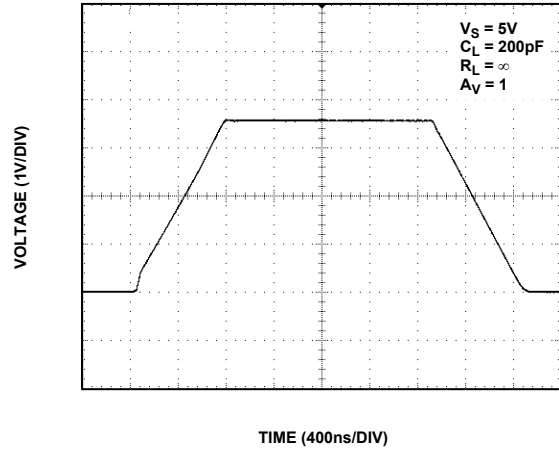


Figure 22. Large Signal Transient Response

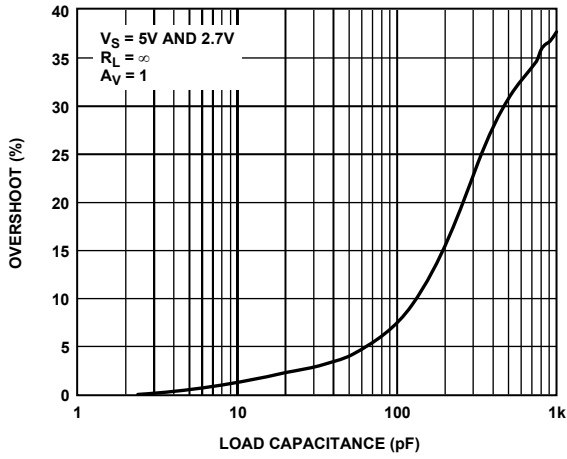


Figure 20. Small Signal Overshoot vs. Load Capacitance

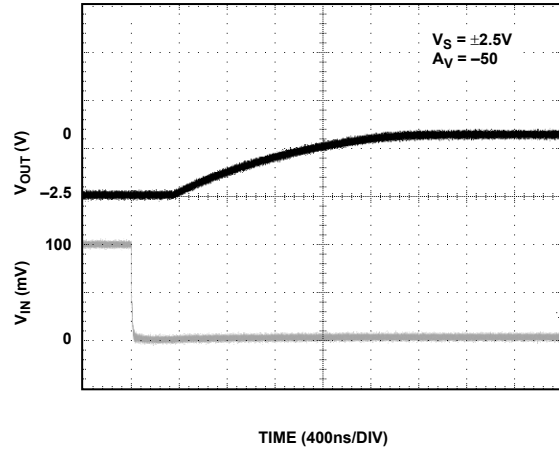


Figure 23. Positive Overload Recovery

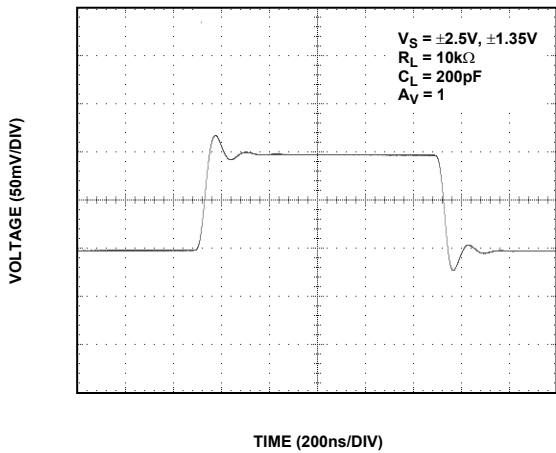


Figure 21. Small Signal Transient Response

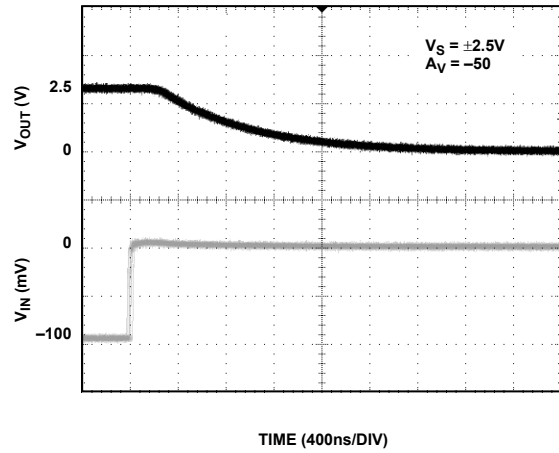


Figure 24. Negative Overload Recovery

04891-015

04891-018

04891-016

04891-019

04891-017

04891-020



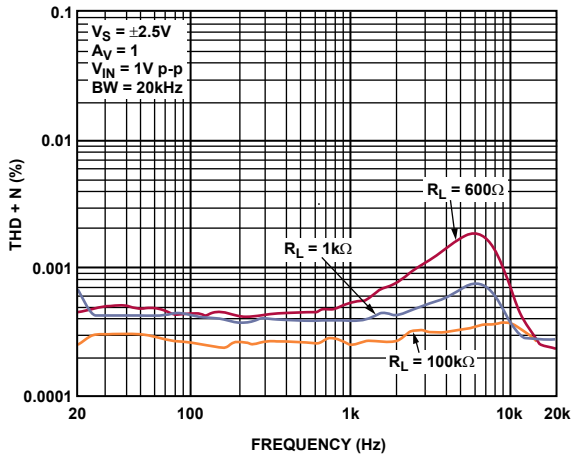


Figure 25. THD + N vs. Frequency

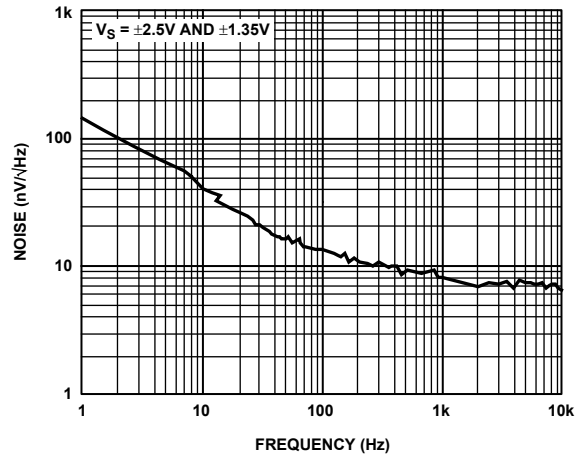


Figure 27. Voltage Noise Density

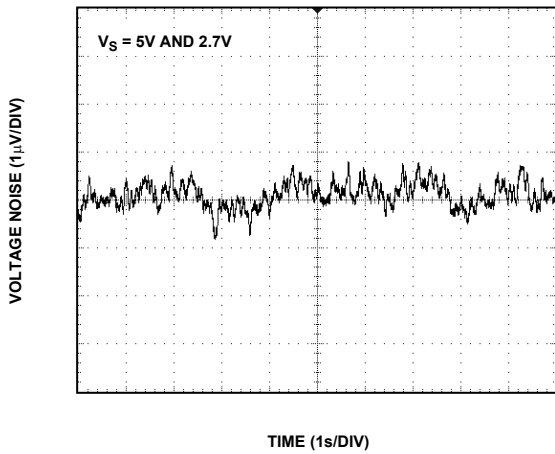


Figure 26. 0.1 Hz to 10 Hz Input Voltage Noise

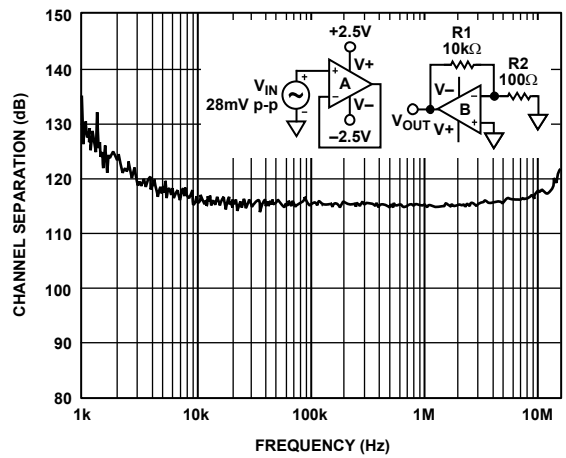


Figure 28. AD8692/AD8694 Channel Separation

# AD8691/AD8692/AD8694

$V_S = +2.7\text{ V}$  or  $\pm 1.35\text{ V}$ , unless otherwise noted.

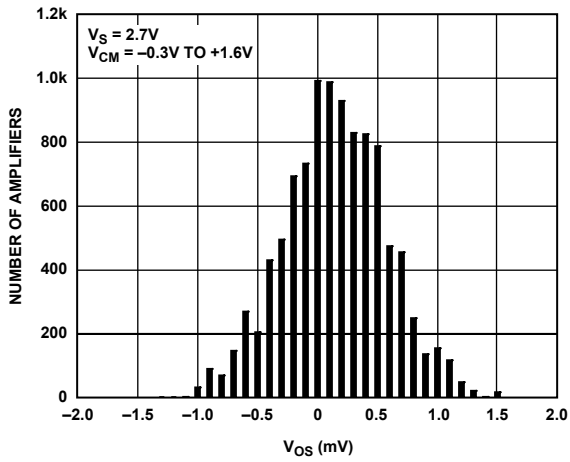


Figure 29. Input Offset Voltage Distribution

04891-025

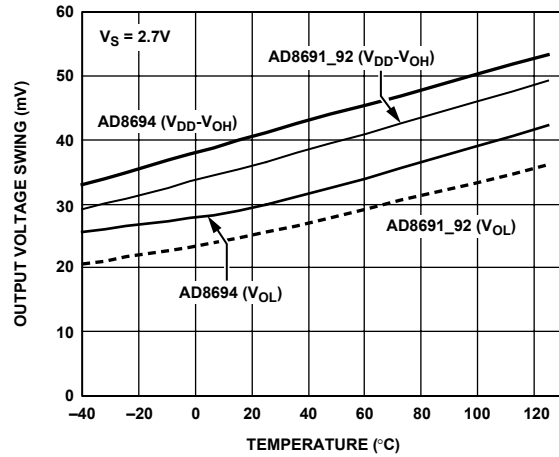


Figure 32. Output Voltage Swing vs. Temperature ( $I_L = 1\text{ mA}$ )

04891-028

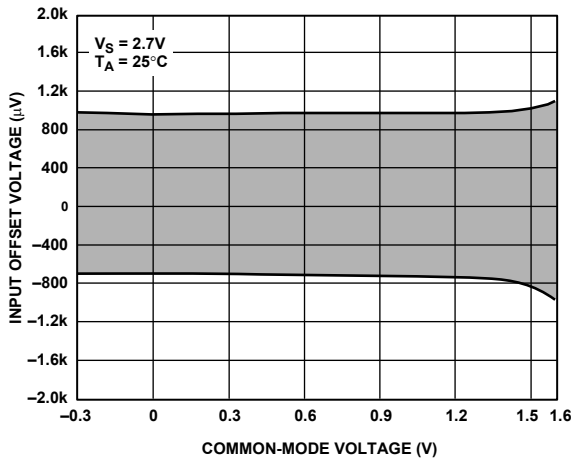


Figure 30. Input Offset Voltage vs. Common-Mode Voltage

04891-026

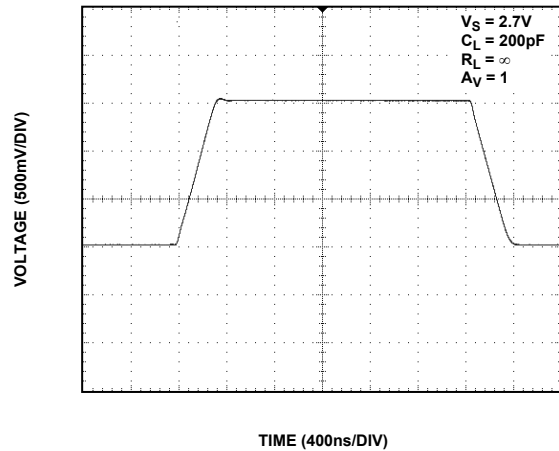


Figure 33. Large Signal Transient Response

04891-029

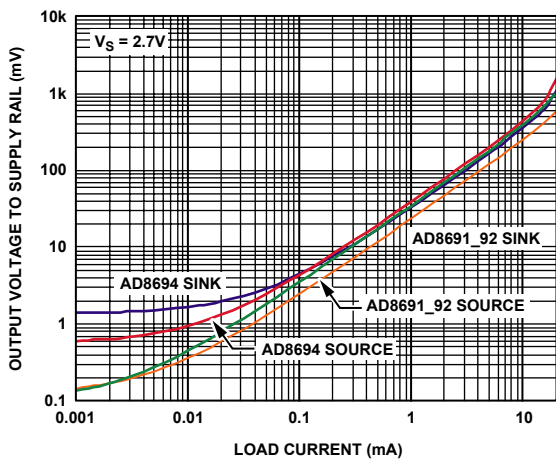


Figure 31. Output Voltage to Supply Rail vs. Load Current

04891-027

# OUTLINE DIMENSIONS

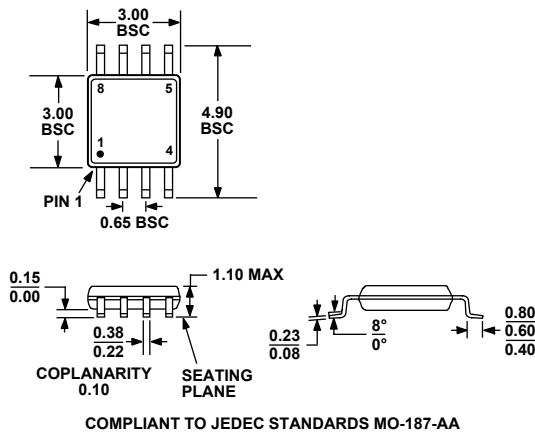


Figure 34. 8-Lead Mini Small Outline Package [MSOP] (RM-8)  
Dimensions shown in millimeters

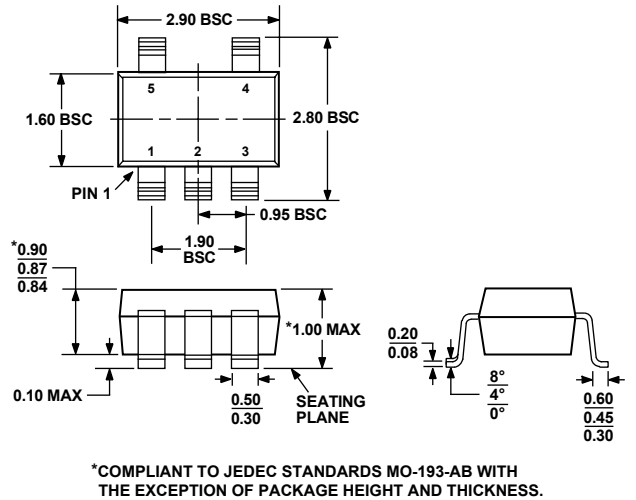


Figure 37. 5-Lead Thin Small Outline Transistor Package [TSOT] (UJ-5)  
Dimensions shown in millimeters

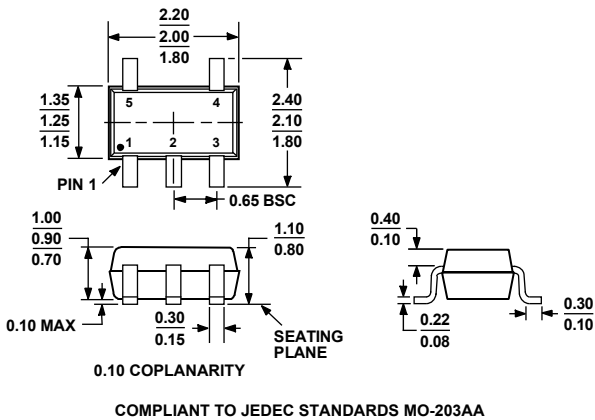


Figure 35. 5-Lead Thin Shrink Small Outline Package [SC70] (KS-5)  
Dimensions shown in millimeters

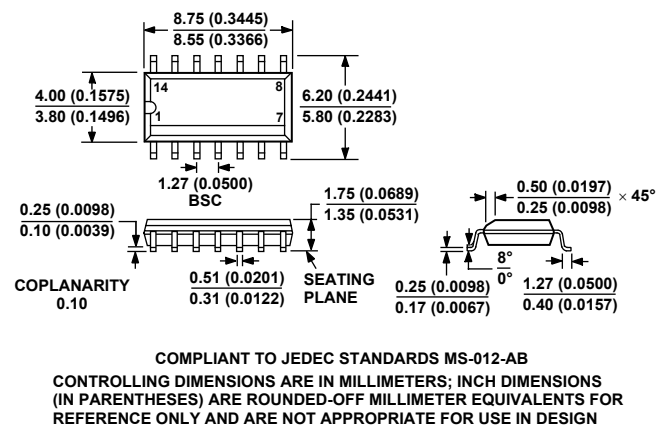


Figure 38. 14-Lead Standard Small Outline Package [SOIC] Narrow Body (R-14)  
Dimensions shown in millimeters

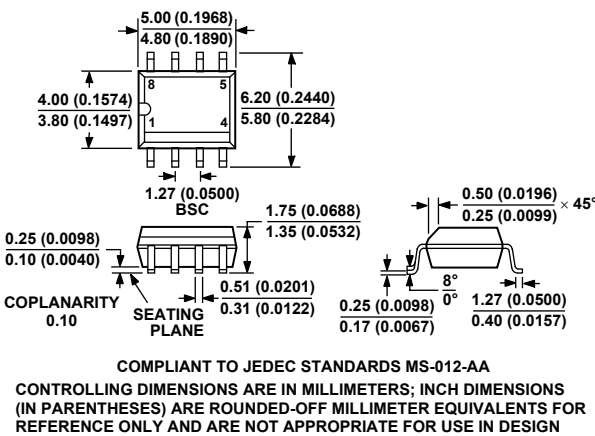


Figure 36. 8-Lead Standard Small Outline Package [SOIC] Narrow Body (R-8)  
Dimensions shown in millimeters and (inches)

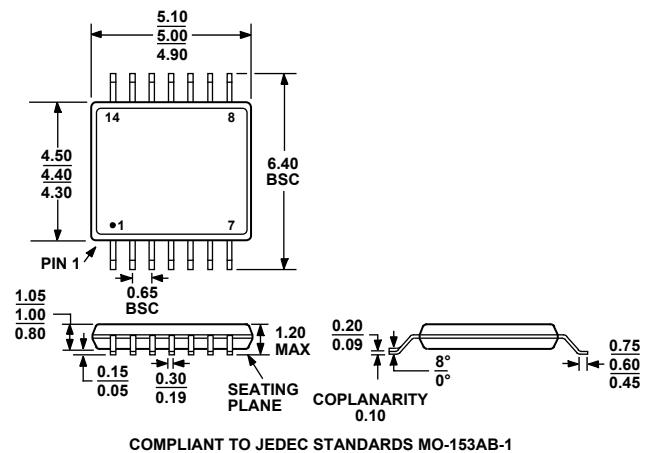


Figure 39. 14-Lead Thin Shrink Small Outline Package [TSSOP] (RU-14)  
Dimensions shown in millimeters

# AD8691/AD8692/AD8694

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
AD8691AUJZ-R2	-40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AUJZ-REEL	-40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AUJZ-REEL7	-40°C to +125°C	5-Lead TSOT	UJ-5	ACA
AD8691AKSZ-R2	-40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8691AKSZ-REEL	-40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8691AKSZ-REEL7	-40°C to +125°C	5-Lead SC70	KS-5	ACA
AD8692ARMZ-R2 <sup>1</sup>	-40°C to +125°C	8-Lead MSOP	RM-8	APA
AD8692ARMZ-REEL	-40°C to +125°C	8-Lead MSOP	RM-8	APA
AD8692ARZ	-40°C to +125°C	8-Lead SOIC	R-8	
AD8692ARZ-REEL	-40°C to +125°C	8-Lead SOIC	R-8	
AD8692ARZ-REEL7	-40°C to +125°C	8-Lead SOIC	R-8	
AD8694ARUZ	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694ARUZ-REEL	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8694ARZ	-40°C to +125°C	14-Lead SOIC	R-14	
AD8694ARZ-REEL	-40°C to +125°C	14-Lead SOIC	R-14	
AD8694ARZ-REEL7	-40°C to +125°C	14-Lead SOIC	R-14	

<sup>1</sup> Z = Pb-free part.